### **Philips Semiconductors**

### Three quadrant triacs guaranteed commutation

### BTA208 series D, E and F

### **GENERAL DESCRIPTION**

### **QUICK REFERENCE DATA**

Passivated guaranteed commutation triacs in a plastic envelope intended for use in motor control circuits or with other highly inductive loads. These devices balance the requirements of commutation performance and gate sensitivity. The "sensitive gate" E series and "logic level" D series are intended for interfacing with low power drivers, including micro controllers.

SYMBOL	PARAMETER	MAX.	MAX.	UNIT
	BTA208- BTA208- BTA208-	600D 600E 600F	- 800E 800F	
$V_{DRM}$	Repetitive peak	600	800	V
I <sub>T(RMS)</sub> I <sub>TSM</sub>	off-state voltages RMS on-state current Non-repetitive peak on-state current	8 65	8 65	A A

### **PINNING - TO220AB**

PIN

1

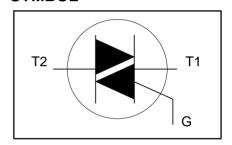
DESCRIPTION	
main terminal 1	

2 main terminal 23 gatetab main terminal 2

### **PIN CONFIGURATION**

# tab 1 2 3

### **SYMBOL**



### **LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MA	X.	UNIT
$V_{DRM}$	Repetitive peak off-state voltages		-	<b>-600</b> 600 <sup>1</sup>	<b>-800</b> 800	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave;	-	8		Α
I <sub>TSM</sub>	Non-repetitive peak on-state current	$T_{mb} \le 102 ^{\circ}\text{C}$ full sine wave; $T_j = 25 ^{\circ}\text{C}$ prior to surge $t = 20 \text{ms}$	-	65		A
l²t dl <sub>⊤</sub> /dt	I <sup>2</sup> t for fusing Repetitive rate of rise of on-state current after triggering	$ \begin{array}{l} t = 16.7 \text{ ms} \\ t = 10 \text{ ms} \\ I_{TM} = 12 \text{ A}; I_{G} = 0.2 \text{ A}; \\ dI_{G}/dt = 0.2 \text{ A}/\mu\text{s} \end{array} $	-	72 21 10	1	Α A²s A/μs
I <sub>GM</sub> V <sub>GM</sub> P <sub>GM</sub> P <sub>G(AV)</sub>	Peak gate current Peak gate voltage Peak gate power Average gate power	over any 20 ms period		2 5 5 0.9		A V W W
$T_{stg}^{stg}$	Storage temperature Operating junction temperature	ponou	-40 -	150 125		°C °C

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<sup>1</sup> Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 6 A/µs.

Philips Semiconductors Objective specification

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### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Thermal resistance junction to mounting base Thermal resistance junction to ambient	full cycle half cycle in free air		- - 60	2.0 2.4 -	K/W K/W K/W

### STATIC CHARACTERISTICS

T<sub>i</sub> = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.		MAX.		UNIT
		BTA208-			D	Е	F	
I <sub>GT</sub>	Gate trigger current <sup>2</sup>	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A T2+ G+ T2+ G- T2- G-	- - -	- - -	5 5 5	10 10 10	25 25 25	mA mA mA
I <sub>L</sub>	Latching current	V <sub>D</sub> = 12 V; I <sub>GT</sub> = 0.1 A T2+ G+ T2+ G- T2- G-	- - -	- - -	15 25 25	20 30 30	25 40 40	mA mA mA
I <sub>H</sub>	Holding current	$V_D = 12 \text{ V}; I_{GT} = 0.1 \text{ A}$	-	-	15	25	30	mA
$V_{T}$ $V_{GT}$	On-state voltage Gate trigger voltage	$I_T = 10 \text{ A}$ $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}$ $V_D = 400 \text{ V}; I_T = 0.1 \text{ A};$	- - 0.25	1.3 0.7 0.4		1.65 1.5 -		V V
I <sub>D</sub>	Off-state leakage current	$T_{j} = 125  ^{\circ}C$ $V_{D} = V_{DRM(max)},$ $T_{j} = 125  ^{\circ}C$	-	0.1		0.5		mA

### **DYNAMIC CHARACTERISTICS**

 $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS		MIN.		TYP.	MAX.	UNIT
		BTA208-	D	Е	F			
dV <sub>D</sub> /dt	Critical rate of rise of off-state voltage	V <sub>DM</sub> = 67% V <sub>DRM(max)</sub> ; T <sub>j</sub> = 110 °C; exponential waveform; gate open circuit	30	60	70		-	V/μs
dI <sub>com</sub> /dt	Critical rate of change of commutating current	$V_{DM} = 400 \text{ V}; T_j = 110 ^{\circ}\text{C};$ $I_{T(RMS)} = 8 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu\text{s};$ gate open circuit	1.8	3.5	4.5		-	A/ms
dI <sub>com</sub> /dt	Critical rate of change of commutating current	$ \begin{vmatrix} V_{\text{DM}} = 400 \text{ V; T}_{j} = 110 \text{ °C;} \\ I_{\text{T(RMS)}} = 8 \text{ A;} \\ dV_{\text{com}}/dt = 0.1 \text{v/}\mu\text{s; gate} \\ \text{open circuit} $	3.5	4.5	5.5		-	A/ms
t <sub>gt</sub>	Gate controlled turn-on time	$egin{align*} I_{TM} = 12 \text{ A; } V_D = V_{DRM(max)}; \\ I_G = 0.1 \text{ A; } dI_G/dt = 5 \text{ A/}\mu s \\ \end{bmatrix}$	-	-	-	2	-	μs

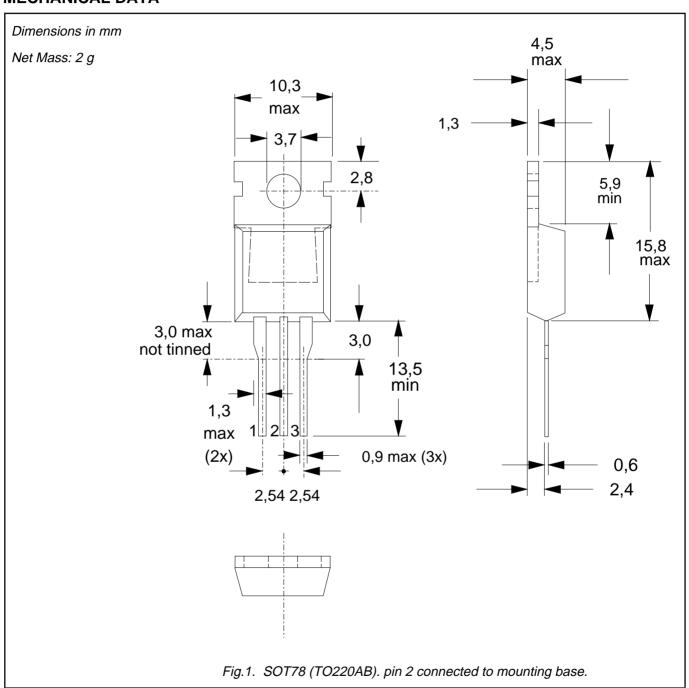
<sup>2</sup> Device does not trigger in the T2-, G+ quadrant.

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### **MECHANICAL DATA**



- Refer to mounting instructions for SOT78 (TO220) envelopes.
   Epoxy meets UL94 V0 at 1/8".

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Objective specification

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### **DEFINITIONS**

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
Limiting values					

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

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